## MSKSEMI















**ESD** 

TVS

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# Broduct data sheet







**SMA** 

## **FEATURES**

- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Low forward voltage drop

### **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.063 grams

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

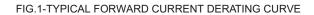
Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	SK32	SK33	SK34	SK35	SK36	SK38	SK39	SK310	UNITS
Maximum Recurrent Peak Reverse Voltage		30	40	50	60	80	90	100	V
Maximum RMS Voltage		21	28	35	42	56	63	70	V
Maximum DC Blocking Voltage		30	40	50	60	80	90	100	V
Maximum Average Forward Rectified Current									
At T <sub>L</sub> =100°C				3	.0				Α
Peak Forward Surge Current, 8.3 ms single half sind	e-wave								
superimposed on rated load (JEDEC method)		80						Α	
Maximum Instantaneous Forward Voltage at 3.0A		0.55 0.70			0.85			V	
Maximum DC Reverse Current Ta=25°	С		0.1				0.02		mA
at Rated DC Blocking Voltage Ta=100	)°C		5				2		mA
Typical Junction Capacitance (Note1)		300						pF	
Typical Thermal Resistance R JL (Note 2)		10						°C/W	
Operating Temperature Range T <sub>J</sub>		-65 —+150						°C	
Storage Temperature Range Tsтg		-65 — +150					°C		

#### NOTES:

- 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 2. Thermal Resistance Junction to Lead.





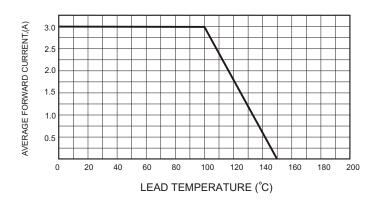


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

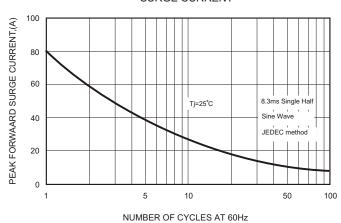


FIG.4-TYPICAL JUNCTION CAPACITANCE

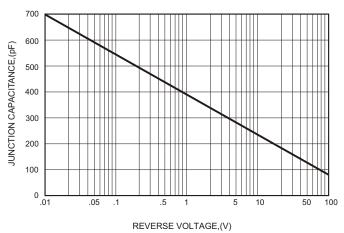


FIG.2-TYPICAL FORWARD

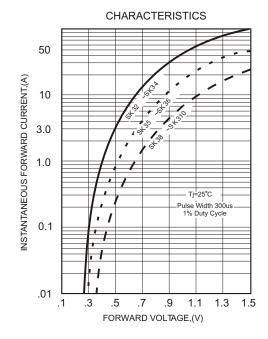
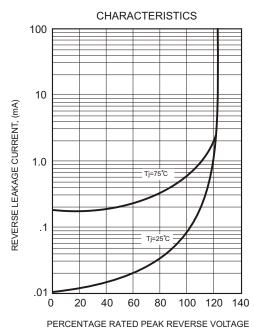
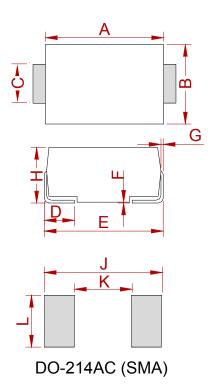


FIG.5 - TYPICAL REVERSE





## **PACKAGE MECHANICAL DATA**



	Dimensions					
Ref.	Millin	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.25	4.65	0.167	0.183		
В	2.50	2.90	0.098	0.114		
С	1.35	1.65	0.053	0.065		
D	0.76	1.52	0.030	0.060		
Е	4.93	5.28	0.194	0.208		
F	0.051	0.203	0.002	0.008		
G	0.15	0.31	0.006	0.012		
Н	1.98	2.41	0.078	0.095		
J	6.50		0.256			
K		2.30		0.090		
L	1.70		0.067			

## **REEL SPECIFICATION**

P/N	PKG	QTY
SK32 THRU SK310	SMA	2000



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